

CW Operation in Distributed Face Cooling Chip

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Ultra-compact pulsed power laser

- Large
- Costly
- Fragile

Ubiquitous power laser

Types of laser configuration

Shape	Rod	Fiber	Thin disk	DFC
Parameter				
Maximum extractable power	$P_{ex} = \frac{8\pi R_f L}{\chi}$	$P_{ex} = \frac{8\pi R_f L}{\chi}$	$P_{ex} = \frac{12R_f}{\chi} \left(\frac{A}{t}\right)$	$P_{ex} = \frac{24NR_f}{\chi} \left(\frac{A}{t}\right)$
Power scalability	poor	high	medium	high
Gain	medium	high	poor	high
Damage threshold	medium	poor	high	high

Heat distribution in DFC chip

OUR AIM

- Tiny-integrated mJ class, sub-ns laser
- Average power over 100 W
- Repetition rate > 10 kHz

Current limitation: heat generation

V. Yahia et al., Opt. Express 26, 8609-8618 (2018)

Heatsink: YAG, Sapphire, Diamond
Gain medium: Nd:YAG, Yb:YAG, Cr:YAG etc.

Coated materials are possible too!!

Surface activated bonding (SAB) technology

Ultra-high vacuum chamber

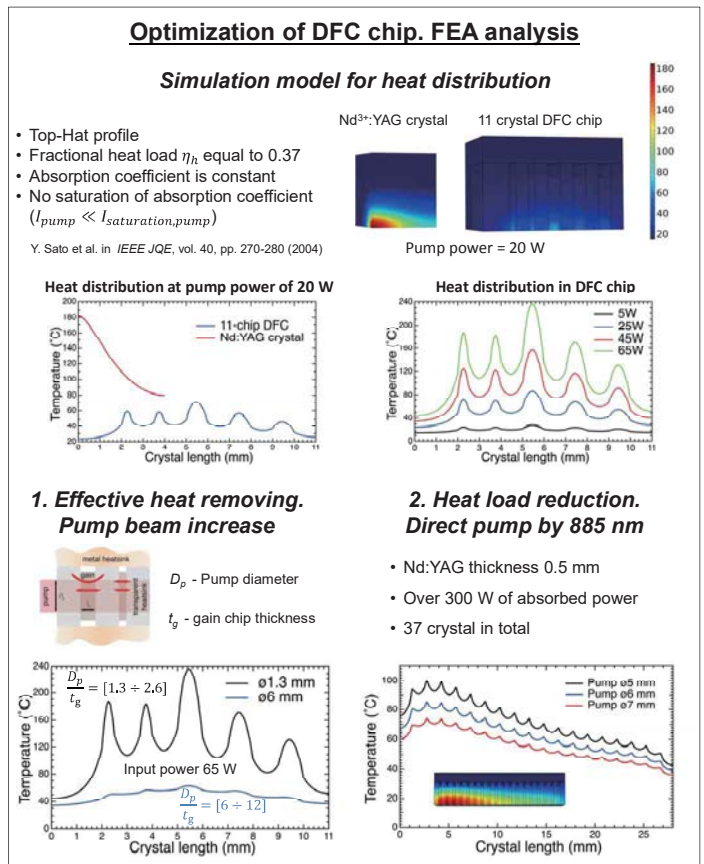
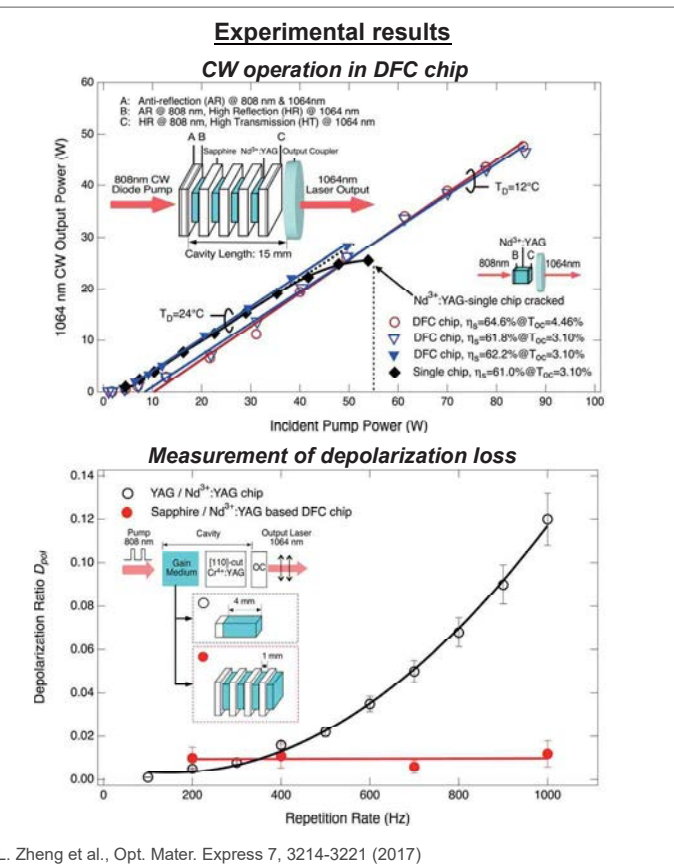
T. Suga et al., Acta Metall. Mater. 40, S133-S137 (1992)

Amorphous layer

Nd:YAG
~18 nm
Sapphire

11-crystal DFC chip

Coated interface



Distributed face cooling method improves CW output by two times